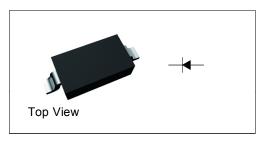


#### Silicon Epitaxial Planar Switching Diode

#### **Features**

- Small plastic package suitable for surface mounted design
- High reliability with high surge current handling capability



Marking Code: A Simplified outline SOD-323 and symbol

# **Applications**

• High speed switching

Absolute Maximum Ratings (T<sub>a</sub> = 25 °C)

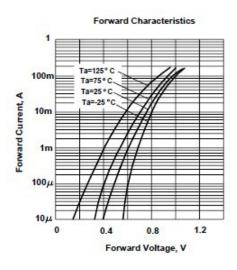
Parameter	Symbol	Value	Unit
Peak Reverse Voltage	$V_{RM}$	90	V
Reverse Voltage	$V_{R}$	80	V
Average Rectified Forward Current	I <sub>F(AV)</sub>	100	mA
Peak Forward Current	I <sub>FM</sub>	225	mA
Surge Forward Current (1 s)	I <sub>FSM</sub>	500	mA
Junction Temperature	Tj	150	°C
Storage Temperature Range	$T_{stg}$	- 55 to + 150	°C

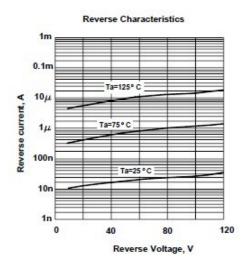
## Electrical Characteristics (T<sub>a</sub> = 25 °C)

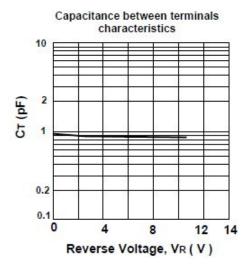
Parameter	Symbol	Max.	Unit
Forward Voltage at I <sub>F</sub> = 100 mA	V <sub>F</sub>	1.2	<b>&gt;</b>
Reverse Current at V <sub>R</sub> = 80 V	I <sub>R</sub>	0.1	μA
Capacitance between Terminals at $V_R = 0.5 V$ , $f = 1 MHz$	Ст	3	pF
Reverse Recovery Time at $V_R$ = 6 V, $I_F$ = 10 mA, $R_L$ = 100 $\Omega$	t <sub>rr</sub>	4	ns

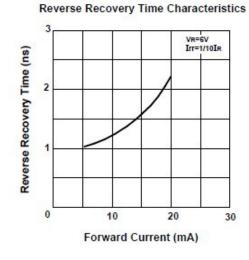
REV.08 1 of 3

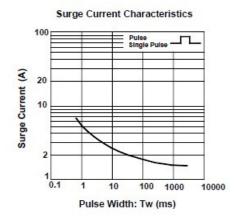


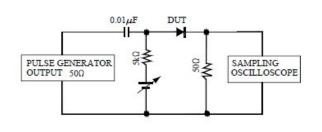












Reverse Recovery Time Measurement Circuit

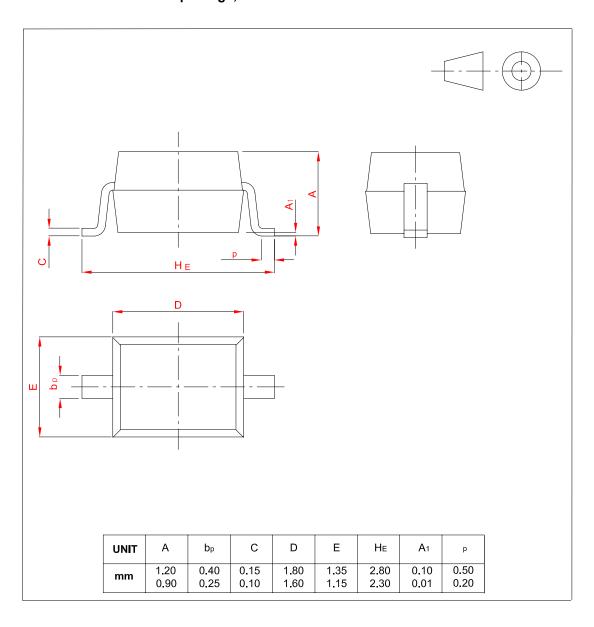
REV.08 2 of 3



## **PACKAGE OUTLINE**

#### Plastic surface mounted package; 2 leads

SOD-323



REV.08 3 of 3